Semiconductor Solutions for High Speed Communication and Fiber Optic Applications

The FOA11002A1 is the industry's lowest power consuming STM64/OC-192 Transimpedance Amplifier for SDH/SONET systems in Silicon Germanium technology. This new device is a key component for future high speed optical communication systems for regional, metropolitan and backbone transport data networks at the highest speeds up to 10.7 Gbit/s over one single fiber. It is a member of the complete 10 Gbit/s chipset in the Silicon Germanium technology.



### **Features**

- Input sensitivity: -18.0 dBm electrical at BER = 10<sup>-12</sup>
- lacktriangle Transimpedance: 6 k $\Omega$
- Overload: o dBm electrical
- Single power supply: +5 V
- Low power consumption: 170 mW
- Internal DC compensation loop increases dynamic range
- Internal bias generation for PIN photo diode including low-pass filter
- Operates with PIN photo diode or APD
- Monitor output for mirrored photodiode current

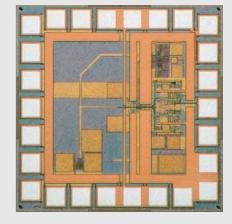
## Typical Applications

- Fiber optics telecom and datacom applications
- SONET/SDH OC-192/STM-64 with and without FEC
- Preamplifier modules
- Optical receiver modules

### Main Advantages

- Data rate from 9.95 Gbit to 10.7 Gbit/s up to 10.7 Gbit/s Input sensitivity:
  - $-18.0 \text{ dBm at BER} = 10^{-12}$
- Transimpedance:  $6 \text{ k}\Omega$
- High overload: 1.5 mA pp maximum input current
- Single power supply: +5 V
- Low power consumption: 170 mW
- Internal DC compensation loop increases dynamic range

- Internal bias generation for PIN photo diode including low-pass filter
- Operates with PIN photo diode or APD
- Monitor output for mirrored photodiode current
- Few external components necessary
- Small chip size of 0.97 x 0.97 mm (available as bare die)



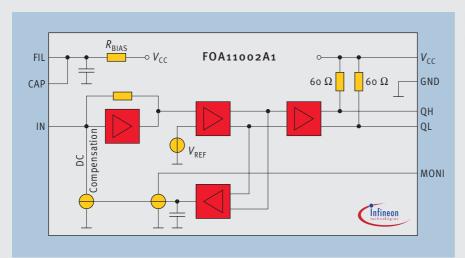
#### **Packing**

Туре	Sales Code	Package
TIA	F0A11002A	Bare die

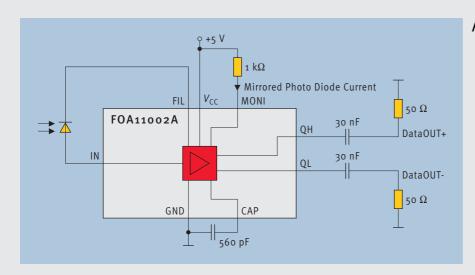
# F O A 1 1 0 0 2 A 1

Transimpedance Amplifier TIA 9.95 - 10.7 Gbit/s, 5.0 V

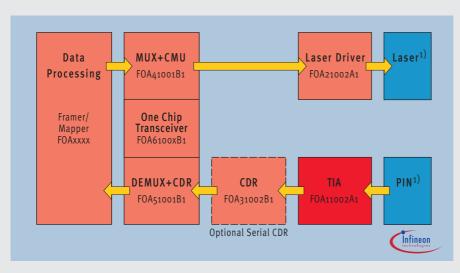




# FOA11002A1 Block Diagram



# Application Example



# 10 Gbit/s Chipset Overview

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### Information

For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office in Germany or our Infineon Technologies Representatives worldwide.

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